

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer



June 2014

FGY75N60SMD 600 V, 75 A Field Stop IGBT

Features

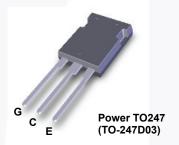
- · High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 1.9 V @ I_C = 75 A
- High Input Impedance
- Fast Switching : E_{OFF} = 10 uJ/A
- RoHS Compliant

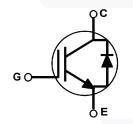
General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 2_{nd} generation IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.

Application

· Solar Inverter, UPS, Welder, SMPS, PFC





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V	Gate to Emitter Voltage		± 20	V
V_{GES}	Transient Gate to Emitter Voltage		± 30	V
I _C	Collector Current	@ T _C = 25°C	150	А
iC	Collector Current	@ T _C = 100°C	75	А
I _{CM (1)}	Pulsed Collector Current @ T _C = 25°C		225	A
I _F	Diode Forward Current	@ T _C = 25°C	75	A
	Diode Forward Current	@ T _C = 100°C	50	Α
I _{FM (1)}	Pulsed Diode Maximum Forward Current		225	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	750	W
י ט	Maximum Power Dissipation	@ T _C = 100°C	375	W
T _J	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature.

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.2	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	-	0.48	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	ing Method Reel Size		Quantity	
FGY75N60SMD	FGY75N60SMD	TO-247D03	O-247D03 Tube N/A		N/A	30	

Electrical Characteristics of the IGBT $T_C = 25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 250 μA	600	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0 V, I_{C} = 250 μ A	-	0.67	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-	-	250	μА
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}$, $V_{CE} = 0 V$	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	$I_C = 250 \mu A, V_{CE} = V_{GE}$	3.5	5.0	6.5	V
		I _C = 75 A, V _{GE} = 15 V	-	1.90	2.50	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 75 A, V _{GE} = 15 V, T _C = 175°C	-	2.14	-	V
Dynamic C	haracteristics			/		
C _{ies}	Input Capacitance		-	3800	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz	-	390	- 7	pF
C _{res}	Reverse Transfer Capacitance	T = 1 MHZ	-	105	- ,, /	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time		-	24	32	ns
t _r	Rise Time	_	-	56	73	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 75 A,	-	136	177	ns
t _f	Fall Time	$R_G = 3 \Omega, V_{GE} = 15 V,$	-	22	29	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	2.3	2.99	mJ
E _{off}	Turn-Off Switching Loss		-	0.77	1.00	mJ
E _{ts}	Total Switching Loss		-	3.07	3.99	mJ
t _{d(on)}	Turn-On Delay Time		-	23	-	ns
t _r	Rise Time	$V_{CC} = 400 \text{ V}, I_{C} = 75 \text{ A},$ $R_{G} = 3 \Omega, V_{GE} = 15 \text{ V},$ Industry $I_{CC} = 170 \Omega$	-	53	-	ns
t _{d(off)}	Turn-Off Delay Time		-	146	-	ns
t _f	Fall Time		-	15	-	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 175°C	-	3.60	-	mJ
E _{off}	Turn-Off Switching Loss		-	1.11	-	mJ
E _{ts}	Total Switching Loss		-	4.71	-	mJ

Electrical Characteristics of the IGBT $T_C = 25^{\circ}C$ unless otherwise noted

Qg	Total Gate Charge		-	248	370	nC
Q_{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 75 A, V _{GE} = 15 V	-	28	42	nC
Q _{gc}	Gate to Collector Charge	VGE 10 V	-	129	195	nC

Electrical Characteristics of the Diode $T_C = 25^{\circ}$ C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Units
V _{FM}	Diode Forward Voltage	I _F = 50 A	T _C = 25°C	-	1.75	2.1	V
			T _C = 175°C	-	1.35	-]
E _{rec}	Reverse Recovery Energy	I _F = 50 A, di _F /dt = 200 A/μs V _R =400 V	T _C = 175°C	-	0.14	-	mJ
t	Diode Reverse Recovery Time		T _C = 25°C	-	41	55	ns
l _{rr}			T _C = 175°C	- 5	126	-	110
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	/-	81	115	nC
⊄ rr			T _C = 175°C	-	736	-	

Figure 1. Typical Output Characteristics

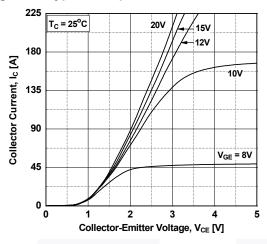


Figure 2. Typical Output Characteristics

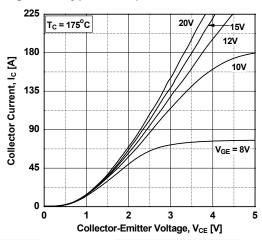


Figure 3. Typical Saturation Voltage Characteristics

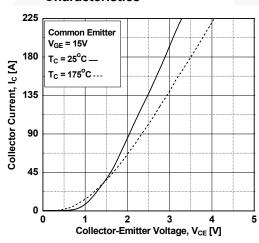


Figure 4. Transfer Characteristics

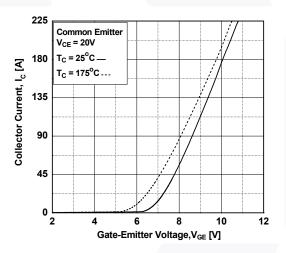


Figure 5. Saturation Voltage vs. Case
Temperature at Variant Current Level

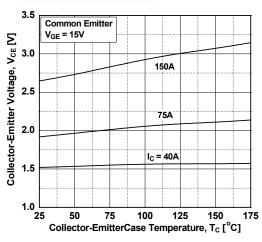


Figure 6. Saturation Voltage vs. V_{GE}

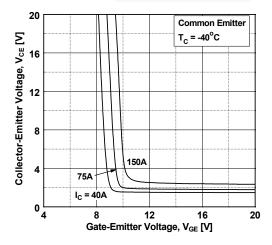


Figure 7. Saturation Voltage vs. V_{GE}

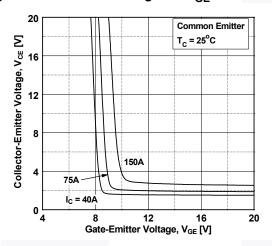


Figure 9. Capacitance Characteristics

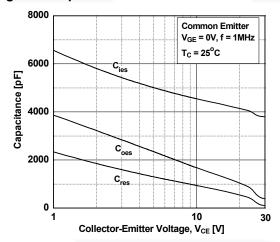


Figure 11. Turn-off Characteristics vs.
Gate Resistance

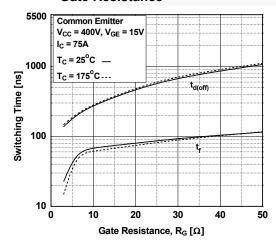


Figure 8. Saturation Voltage vs. V_{GE}

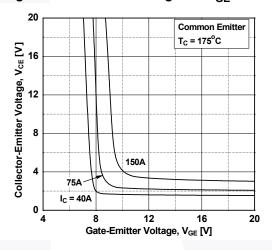


Figure 10. Gate charge Characteristics

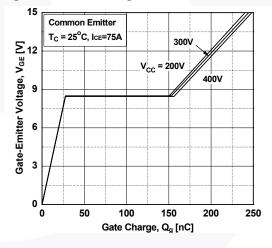


Figure 12. Turn-on Characteristics vs.
Gate Resistance

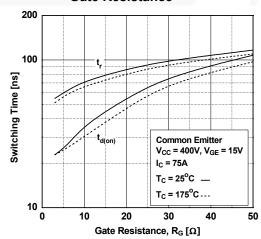


Figure 13. Turn-off Characteristics vs. Collector Current

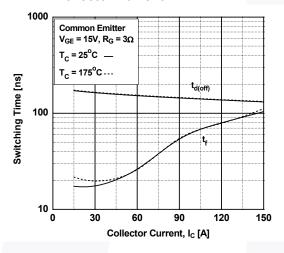


Figure 14. Turn-on Characteristics vs. Collector Current

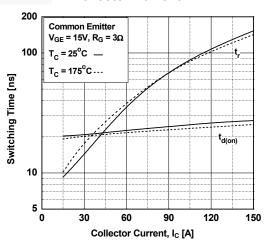


Figure 15. Switching Loss vs. Collector Current

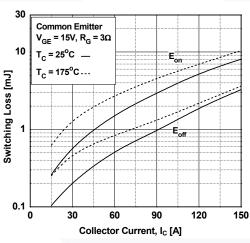


Figure 16. Switching Loss vs. Gate Resistance

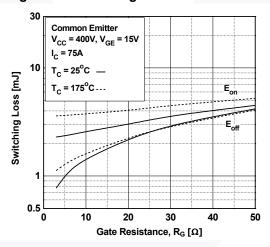


Figure 17. SOA Characteristics

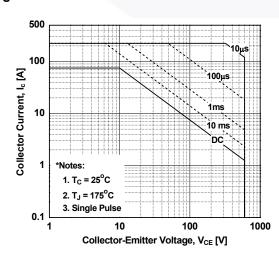


Figure 18. Turn off Switching SOA Characteristics

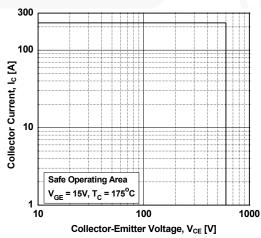


Figure 19. Current Derating

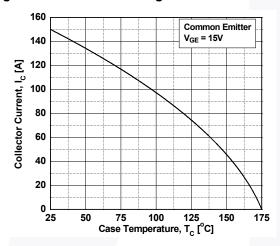


Figure 21. Forward Characteristics

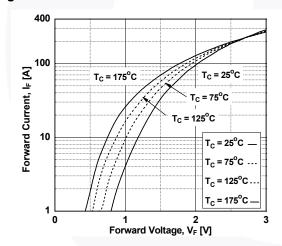


Figure 23. Stored Charge

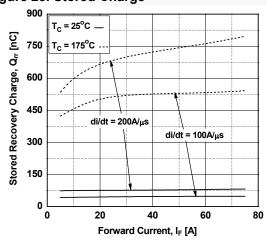


Figure 20. Load Current vs. Frequency

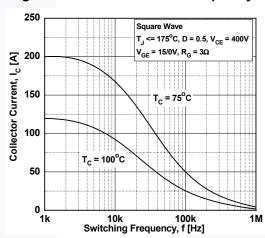


Figure 22. Reverse Current

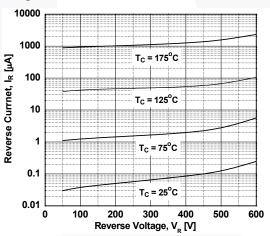


Figure 24. Reverse Recovery Current

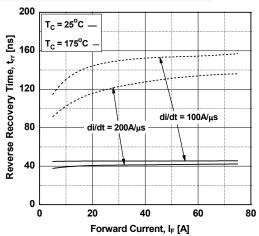


Figure 25. Transient Thermal Impedance of IGBT

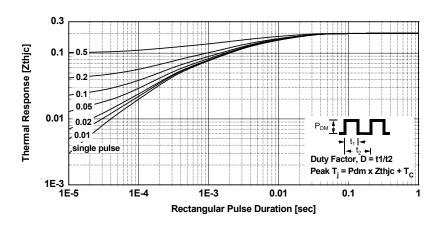
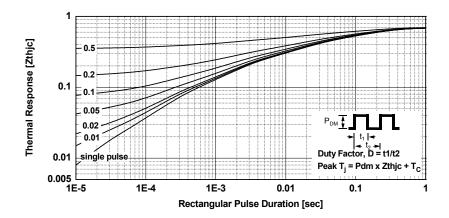


Figure 26. Transient Thermal Impedance of Diode



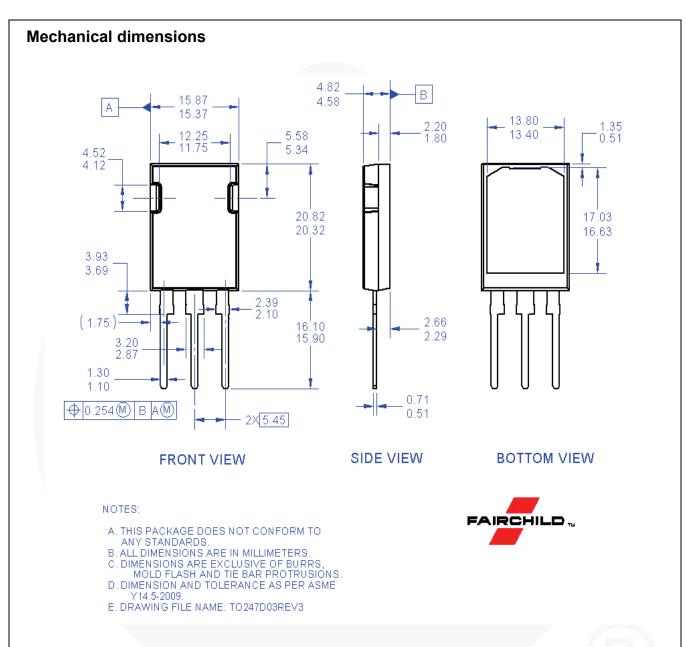


Figure 27. TO-247 3L - 3LDS, POWER TO247, NON JEDEC

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

 $\underline{http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TP247-003\#}$





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

intended to be an exhaustive
AccuPower™
AX-CAP®*
BitSiC™
Build it Now™
CorePLUS™
CorePCWER™
CROSSVOLT™

CTL™
Current Transfer Logic™
DEUXPEED®
Dual Cool™
EcoSPARK®
EfficentMax™

ESBC™

R

Fairchild®

Fairchild®

Fairchild Semiconductor[®]
FACT Quiet Series™
FACT[®]
FAST[®]
FastvCore™

F-PFS™ FRFET® Global Power ResourceSM GreenBridge™

Green FPS™ e-Series™

Gmax[™] GTO™ IntelliMAX[™] ISOPLANAR[™]

Marking Small Speakers Sound Louder and Better $^{\text{TM}}$

MegaBuck™
MICROCOUPLER™
MicroFET™
MicroPak™
MicroPak2™
MillerDrive™
MotionMax™
mWSaver®
OptoHiT™
OPTOLOGIC®
OPTOPLANAR®

® PowerTrench® PowerXS™

Programmable Active Droop $^{\text{TM}}$ QFET $^{\text{®}}$

QS™ Quiet Series™ RapidConfigure™

SmartMax™

SyncFET™

Sync-Lock™

Saving our world, 1mW/W/kW at a time™ SignalWise™

SMART START™
Solutions for Your Success™
SPM®
STEALTH™
SuperFET®
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SuperMOS®

SYSTEM ®*
GENERAL
TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TINYOPTO™
TinyPOWOR™
TinyPWMT™
TinyPWITT
TranSiC™
TriFault Detect™
TRUECURRENT®*

µSerDes™

Scribes*
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
VoltagePlus™
XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FETBench™

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; REITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN. WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 168

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and exp

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi

FGY75N60SMD